From basic electrical concepts to equivalent circuits that models physical phenomena



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International Weeh 2nd ATHENA International Weeh

Basic electrical elements in circuit theory

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Basic electrical elements in circuit theory



Basic electrical elements in circuit theory



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INTRODUCTION Basic electrical elements in circuit theory



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$$v(t) = \frac{d\varphi(t)}{dt} \qquad i(t) = \frac{dq(t)}{dt}$$
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• Analysis of constitutive equations and aspects of **linearity and time-variance**.

v-i characteristic: From linear to nonlinear concepts

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v(t) = Ri(t) or i(t) = Gv(t)

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q-v characteristic

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q-v characteristic



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q-v characteristic

i (t)



• Time-varying capacitors

q-v characteristic



q-v characteristic



q-v characteristic



φ-i characteristic

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$$\xrightarrow{i(t)} L$$

$$\xrightarrow{+ v(t)} -$$



φ-i characteristic



φ-i characteristic



φ-i characteristic



• Time-varying inductors

φ-i characteristic



φ-i characteristic


INDUCTOR

φ-i characteristic



Laplace transform techniques in electrical circuits

Laplace transform techniques in electrical circuits

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Laplace transform techniques in electrical circuits



Laplace transform techniques in electrical circuits



Laplace transform techniques in electrical circuits







Analysis in time- and s-domain



Concept of transfer function

























SECOND-ORDER CIRCUITS RLC circuit

RLC circuit



RLC circuit



$$\frac{V_{\rm C}(s)}{V_{\rm i}(s)} = \frac{\frac{1}{LC}}{s^2 + \frac{R}{L}s + \frac{1}{LC}}$$

RLC circuit



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RLC circuit



$$v_{i}(t) = Vu(t) \rightarrow V_{i}(s) = \frac{V}{s}$$

$$v_{\rm c}(t) = v_{\rm c,t}(t) + v_{\rm c,ss}(t)$$

$$\frac{V_{\rm C}(s)}{V_{\rm i}(s)} = \frac{\frac{1}{LC}}{s^2 + \frac{R}{L}s + \frac{1}{LC}}$$

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PRACTICAL EXAMPLES RLC circuit

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Defibrillator

Device that gives a high energy electric shock to the heart of someone who is in cardiac arrest.

PRACTICAL EXAMPLES

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Defibrillator

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Transcranial magnetic stimulation (TMS)

Noninvasive procedure that uses magnetic fields to stimulate nerve cells in the brain to improve symptoms of depression.



PRACTICAL EXAMPLES

RLC circuit





FREQUENCY RESPONSE

Nyquist plots













Application in neurosciences

Application in neurosciences



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Membrane capacitance

Phospholipid bilayer acts as a dielectric wall that separates the charge that exists in the cytoplasm from that in the extracellular matrix

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Selective permeabilities of the membrane to the different ionic species.

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BIOLOGICAL TISSUE

Monitoring physiological states

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BIOLOGICAL TISSUE Monitoring physiological states

E. Hernández-Balaguera et al. J. Electrochem. Society 165(12) (2018) G3099









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Recognition of interfacial events







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CE





Physical interpretation in solar cells

Physical interpretation in solar cells



Physical interpretation in solar cells



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Today Energy 27 (2022) 101031

78 (2020) 105398







Physical interpretation in solar cells



Physical interpretation in solar cells



From ideal to anomalous dynamics









E. Hernández-Balaguera et al. Advanced Materials Interfaces 9(9) (2022) 2102275





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IN THE "REAL WORLD"



16

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$$Z(j\omega) = \frac{1}{Q(j\omega)^{\alpha}} + v(t)$$

• Time-domain:

$$i(t) = Q \frac{d^{\alpha}v(t)}{dt^{\alpha}} + v(t)$$

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+
$$v(t)$$
 -
i(t)
CPE (Q, α)

- Parameters and units:
 - Q: CPE parameter $[\Omega^{-1} s^{\alpha}]$.
 - α : CPE exponent [Dimensionless], $-1 \le \alpha \le 1$.
- $\alpha = 0$: Resistance, R=1/Q.
- $\alpha = 1$: Pure capacitance, C=Q.
- $\alpha = -1$: Inductance, L=1/Q.
- Intermediate values:
 - α = 0.5: Warburg impedance (infinite RC transmission line with uniform distribution).

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In the analysis of the electrical behavior of natural systems, it is generally considered a fractional (or non-integer order) capacitor $(0 < \alpha < 1)$.

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$$Z(j\omega) = \frac{1}{\underbrace{Q\omega^{\alpha}}_{R(\omega)}} \cos(\alpha\pi/2) - j\underbrace{\frac{1}{Q\omega^{\alpha}}_{-X(\omega)}} \sin(\alpha\pi/2)$$



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• Fractal impedance scaling in frequency:

$$Z(jk\omega) = \frac{1}{Q(jk\omega)^{\alpha}} = k^{-\alpha}Z(j\omega)$$

• Self-similarity:

$$\frac{Z(j\omega)}{Z(jk\omega)} =$$



Transient response ($0 < \alpha < 1$)

• Fractional ordinary differential equation, with constant coefficients:

$$\frac{\mathrm{d}^{\alpha} \mathbf{x}(\mathbf{t})}{\mathrm{d} \mathbf{t}^{\alpha}} + \frac{\mathbf{x}(\mathbf{t})}{\tau^{\alpha}} = 0; \quad 0 < \alpha < 1$$

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 - (i) α exponent (Dimensional criteria).
 - (ii) Distributed relaxation times with a discernible average value experimentally measured:

$$\tau = \left(R_{Th}Q\right)^{1/\alpha}$$

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$$E_{\alpha}[-(t/\tau)^{\alpha}] = \sum_{k=0}^{\infty} \frac{[-(t/\tau)^{\alpha}]^{k}}{\Gamma(\alpha k+1)}$$

 $\alpha = 1$: Exponential function

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Characteristic time scales

$$E_{\alpha}\left[-\binom{t}{\tau}^{\alpha}\right] = \sum_{k=0}^{\infty} \frac{\left[-\binom{t}{\tau}^{\alpha}\right]^{k}}{\Gamma(\alpha k+1)} \qquad E_{\alpha}\left[-\binom{t}{\tau}^{\alpha}\right] \sim \begin{cases} 1 - \frac{\binom{t}{\tau}^{\alpha}}{\Gamma(\alpha+1)} + \dots \sim \exp\left[-\frac{\binom{t}{\tau}^{\alpha}}{\Gamma(\alpha+1)}\right], \quad \binom{t}{\tau} \rightarrow 0^{+} \\ \frac{\binom{t}{\tau}^{\gamma}^{-\alpha}}{\Gamma(1-\alpha)} \sim \frac{\operatorname{sen}(\alpha \pi)}{\pi} \binom{\tau}{t}^{\alpha} \Gamma(\alpha), \quad \binom{t}{\tau} \rightarrow \infty \end{cases}$$

Mittag-Leffler function vs. exponential behavior

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Mittag-Leffler function vs. exponential behavior



Mittag-Leffler function vs. exponential behavior



Mittag-Leffler function "draws" a transition from KWW ("stretched exponential", t^{α}) to an inverse power-law function, $t^{-\alpha}$.

et al. Communications in Nonlinear Science and numerical simulations 90 (2020) 105371 Communications in Nonlinear Science and Numerical Simulation



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